# NSN 5962-00-148-2891

Memory Microcircuit - Page 1 of 2



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# **Body Length:**

Between 0.240 inches and 0.275 inches

# Body Width:

Between 0.240 inches and 0.260 inches

# **Body Height:**

Between 0.030 inches and 0.070 inches

# **Maximum Power Dissipation Rating:**

450.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and monolithic and positive outputs and programmable and programmed and w/storage

#### **Inclosure Material:**

# Ceramic and glass

Inclosure Configuration:

Flat pack

#### **Output Logic Form:**

Current-mode logic

## Input Circuit Pattern:

6 input

#### Case Outline Source And Designator:

T0-86 joint electron device engineering council

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

60.0 volts power source

#### Time Rating Per Chacteristic:

10.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Diode matrix

#### Test Data Document:

42470-80000058 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

# etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

14 flat leads

Shelf Life:

N/a

### Unit Of Measure:

- --
- Demilitarization:
- Yes demil/mli

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Memory Microcircuit - Page 2 of 2

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